## NSN 5961-01-044-9044

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Inclosure Material:	
Metal all transistor	
Overall Length:	
0.175 inches all transistor and 0.205 inches all transistor	
Terminal Length:	
0.500 inches all transistor	
Overall Height:	
0.170 inches all transistor and 0.210 inches all transistor	
Overall Width:	
0.125 inches all transistor and 0.165 inches all transistor	
Internal Configuration:	
Junction contact all transistor	
Joint Electronic Device Engineering Council/jedec/case	Outline Designation:
To-92 all transistor	
Internal Junction Configuration:	
Pnp all transistor	
Component Function Relationship:	
Matched	
Component Name And Quantity:	
2 transistor	
Mounting Method:	
Terminal all transistor	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon all transistor	
Voltage Rating In Volts Per Characteristic:	
-25.0 breakdown voltage, collector-to-base, emitter open a	Il transistor and -25.0 breakdown voltage, collector-to-emitter, base open a
transistor	
Current Rating Per Characteristic:	
-800.00 milliamperes source cutoff current all transistor	
Power Rating Per Characteristic:	
620.0 milliwatts small-signal input power, common-collector	absolute all transistor
Maximum Operating Tempurature Per Measurement Poir	nt:
150.0 degrees celsius junction all transistor	
Terminal Type And Quantity:	
3 uninsulated wire lead all transistor	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	

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